

# MCR69-2, MCR69-3

## Silicon Controlled Rectifiers

### Reverse Blocking Thyristors

Designed for overvoltage protection in crowbar circuits.

- Glass-Passivated Junctions for Greater Parameter Stability and Reliability
- Center-Gate Geometry for Uniform Current Spreading Enabling High Discharge Current
- Small Rugged, Thermowatt Package Constructed for Low Thermal Resistance and Maximum Power Dissipation and Durability
- High Capacitor Discharge Current, 750 Amps
- Device Marking: Logo, Device Type, e.g., MCR69-2, Date Code

**MAXIMUM RATINGS** ( $T_J = 25^\circ\text{C}$  unless otherwise noted)

| Rating   | Symbol                   | Value          | Unit                 |
|--|--------------------------|----------------|----------------------|
| Peak Repetitive Off-State Voltage <sup>(1)</sup><br>( $T_J = -40$ to $+125^\circ\text{C}$ , Gate Open)<br>MCR69-2<br>MCR69-3 | $V_{DRM}$ ,<br>$V_{RRM}$ | 50<br>100      | Volts                |
| Peak Discharge Current <sup>(2)</sup>  | $I_{TM}$                 | 750            | Amps                 |
| On-State RMS Current<br>(180° Conduction Angles; $T_C = 85^\circ\text{C}$ )  | $I_T(\text{RMS})$        | 25             | Amps                 |
| Average On-State Current<br>(180° Conduction Angles; $T_C = 85^\circ\text{C}$ )  | $I_T(\text{AV})$         | 16             | Amps                 |
| Peak Non-Repetitive Surge Current<br>(1/2 Cycle, Sine Wave, 60 Hz,<br>$T_J = 125^\circ\text{C}$ )                            | $I_{TSM}$                | 300            | Amps                 |
| Circuit Fusing Considerations<br>( $t = 8.3$ ms)   | $I^2t$                   | 375            | $\text{A}^2\text{s}$ |
| Forward Peak Gate Current<br>( $t \leq 1.0 \mu\text{s}$ , $T_C = 85^\circ\text{C}$ )   | $I_{GM}$                 | 2.0            | Amps                 |
| Forward Peak Gate Power<br>( $t \leq 1.0 \mu\text{s}$ , $T_C = 85^\circ\text{C}$ )   | $P_{GM}$                 | 20             | Watts                |
| Forward Average Gate Power<br>( $t = 8.3$ ms, $T_C = 85^\circ\text{C}$ )   | $P_{G(\text{AV})}$       | 0.5            | Watt                 |
| Operating Junction Temperature Range   | $T_J$                    | -40 to<br>+125 | $^\circ\text{C}$     |
| Storage Temperature Range  | $T_{stg}$                | -40 to<br>+150 | $^\circ\text{C}$     |
| Mounting Torque  | —                        | 8.0            | in. lb.              |

(1)  $V_{DRM}$  and  $V_{RRM}$  for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

(2) Ratings apply for  $t_w = 1$  ms. See Figure 1 for  $I_{TM}$  capability for various duration of an exponentially decaying current waveform,  $t_w$  is defined as 5 time constants of an exponentially decaying current pulse.

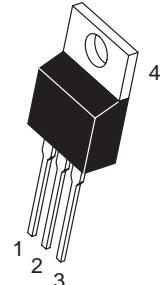
(3) Test Conditions:  $I_G = 150$  mA,  $V_D = \text{Rated } V_{DRM}$ ,  $I_{TM} = \text{Rated Value}$ ,  $T_J = 125^\circ\text{C}$ .



**KERSEMI**

[www.kersemi.com](http://www.kersemi.com)

**SCRs**  
**25 AMPERES RMS**  
**50 thru 100 VOLTS**



**TO-220AB  
CASE 221A  
STYLE 3**

| PIN ASSIGNMENT |         |
|----------------|---------|
| 1              | Cathode |
| 2              | Anode   |
| 3              | Gate    |
| 4              | Anode   |

### ORDERING INFORMATION

| Device  | Package | Shipping |
|---------|---------|----------|
| MCR69-2 | TO220AB | 500/Box  |
| MCR69-3 | TO220AB | 500/Box  |

# MCR69-2, MCR69-3

## THERMAL CHARACTERISTICS

| Characteristic  | Symbol          | Max | Unit |
|---|-----------------|-----|------|
| Thermal Resistance, Junction to Case  | $R_{\theta JC}$ | 1.5 | °C/W |
| Thermal Resistance, Junction to Ambient                                       | $R_{\theta JA}$ | 60  | °C/W |
| Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds | $T_L$           | 260 | °C   |

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ C$ unless otherwise noted.)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

## OFF CHARACTERISTICS

|   |                     |                    |   |   |     |    |
|---|---------------------|--------------------|---|---|-----|----|
| Peak Repetitive Forward or Reverse Blocking Current<br>( $V_AK$ = Rated $V_{DRM}$ or $V_{RRM}$ , Gate Open) | $T_J = 25^\circ C$  | $I_{DRM}, I_{RRM}$ | — | — | 10  | μA |
|   | $T_J = 125^\circ C$ |                    | — | — | 2.0 | mA |

## ON CHARACTERISTICS

|  |          |     |      |     |       |
|--|----------|-----|------|-----|-------|
| Peak Forward On-State Voltage<br>( $I_{TM} = 50 A$ )(1)<br>( $I_{TM} = 750 A, t_w = 1 ms$ )(2)             | $V_{TM}$ | —   | —    | 1.8 | Volts |
| Gate Trigger Current (Continuous dc)<br>( $V_D = 12 V, R_L = 100 \Omega$ )                                 | $I_{GT}$ | 2.0 | 7.0  | 30  | mA    |
| Gate Trigger Voltage (Continuous dc)<br>( $V_D = 12 V, R_L = 100 \Omega$ )                                 | $V_{GT}$ | —   | 0.65 | 1.5 | Volts |
| Gate Non-Trigger Voltage<br>( $V_D = 12 Vdc, R_L = 100 \Omega, T_J = 125^\circ C$ )                        | $V_{GD}$ | 0.2 | 0.40 | —   | Volts |
| Holding Current<br>( $V_D = 12 V$ , Initiating Current = 200 mA, Gate Open)                                | $I_H$    | 3.0 | 15   | 50  | mA    |
| Latching Current<br>( $V_D = 12 Vdc, I_G = 150 mA$ )   | $I_L$    | —   | —    | 60  | mA    |
| Gate Controlled Turn-On Time(3)<br>( $V_D$ = Rated $V_{DRM}$ , $I_G = 150 mA$ )<br>( $I_{TM} = 50 A$ Peak) | $t_{gt}$ | —   | 1.0  | —   | μs    |

## DYNAMIC CHARACTERISTICS

|  |         |    |   |     |           |
|--|---------|----|---|-----|-----------|
| Critical Rate-of-Rise of Off-State Voltage<br>( $V_D$ = Rated $V_{DRM}$ , Gate Open, Exponential Waveform, $T_J = 125^\circ C$ ) | $dv/dt$ | 10 | — | —   | $V/\mu s$ |
| Critical Rate-of-Rise of On-State Current<br>$I_G = 150 mA$  | $di/dt$ | —  | — | 100 | $A/\mu s$ |

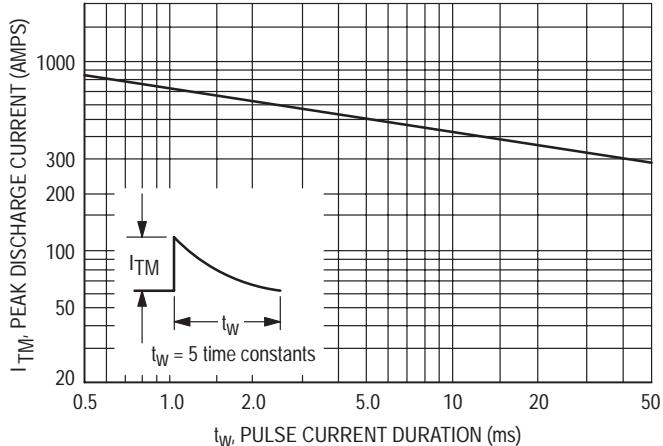
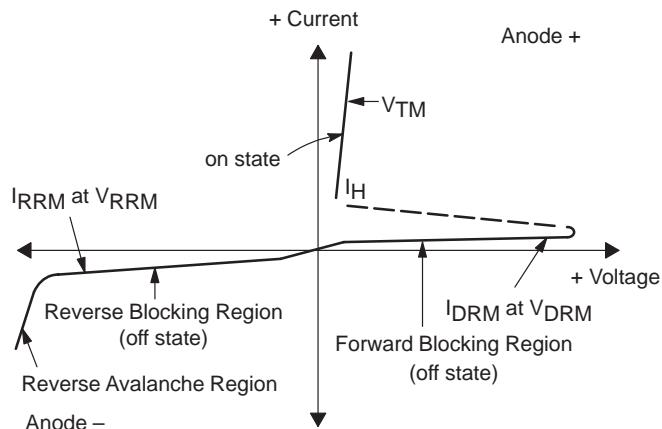
(1) Pulse duration  $\leq 300 \mu s$ , duty cycle  $\leq 2\%$ .

(2) Ratings apply for  $t_w = 1 ms$ . See Figure 1 for  $I_{TM}$  capability for various durations of an exponentially decaying current waveform.  $t_w$  is defined as 5 time constants of an exponentially decaying current pulse.

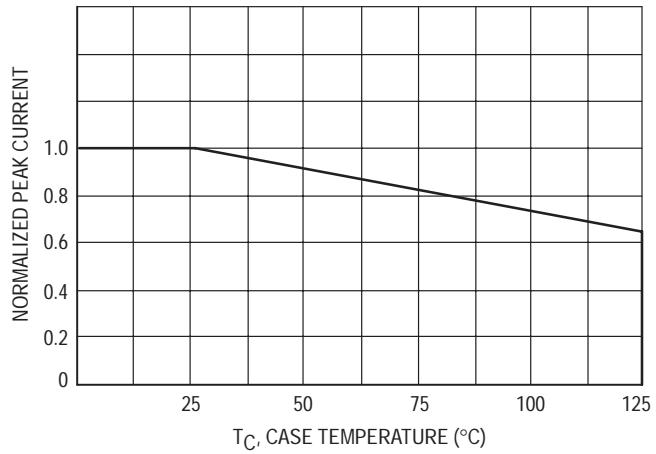
(3) The gate controlled turn-on time in a crowbar circuit will be influenced by the circuit inductance.

**Voltage Current Characteristic of SCR**

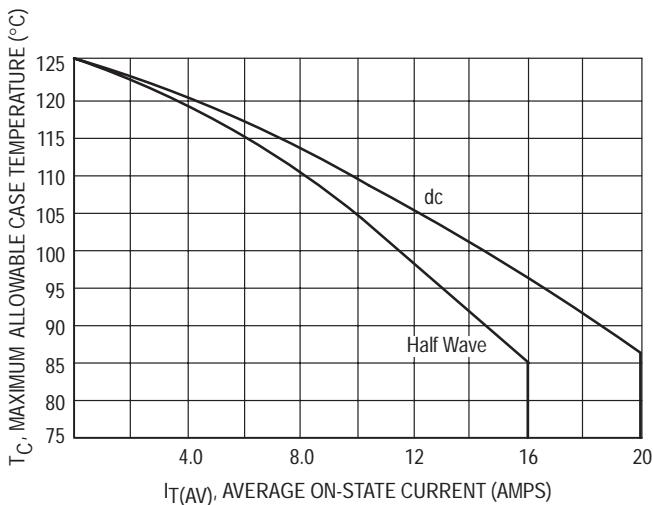
| Symbol    | Parameter                                 |
|-----------|---|
| $V_{DRM}$ | Peak Repetitive Off State Forward Voltage |
| $I_{DRM}$ | Peak Forward Blocking Current             |
| $V_{RRM}$ | Peak Repetitive Off State Reverse Voltage |
| $I_{RRM}$ | Peak Reverse Blocking Current             |
| $V_{TM}$  | Peak On State Voltage                     |
| $I_H$     | Holding Current                           |



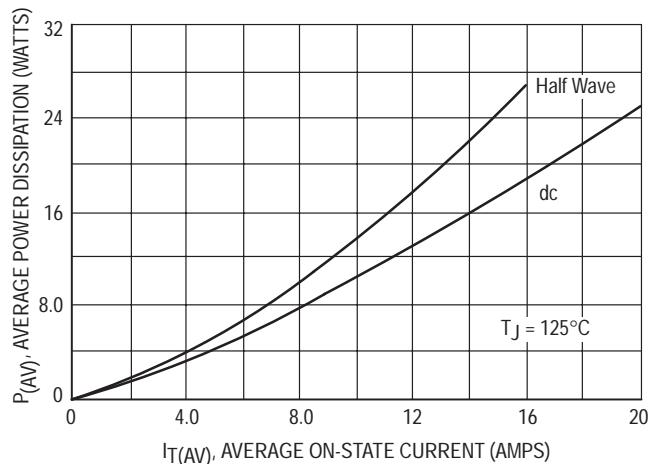
**Figure 1. Peak Capacitor Discharge Current**



**Figure 2. Peak Capacitor Discharge Current Derating**



**Figure 3. Current Derating**



**Figure 4. Maximum Power Dissipation**

## MCR69-2, MCR69-3

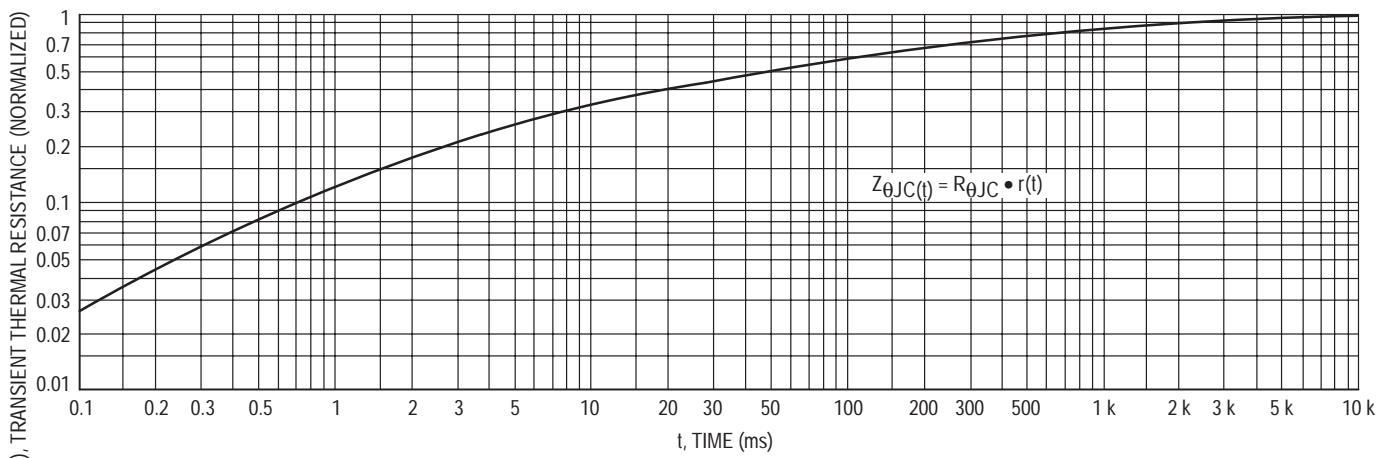


Figure 5. Thermal Response

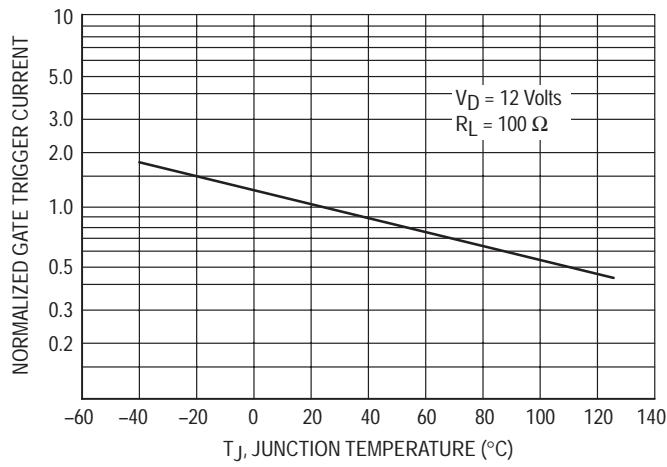


Figure 6. Gate Trigger Current

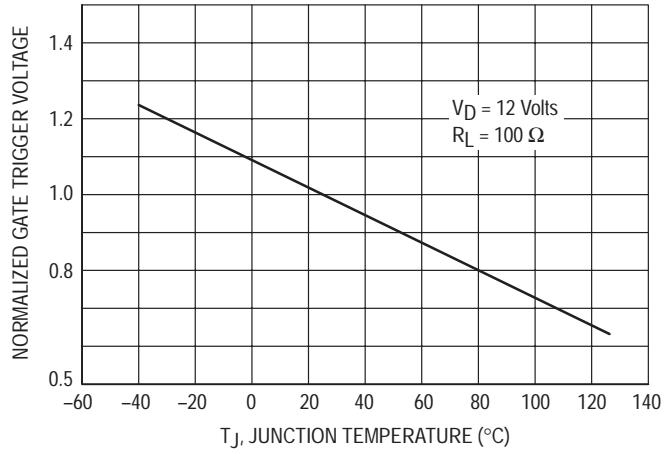


Figure 7. Gate Trigger Voltage

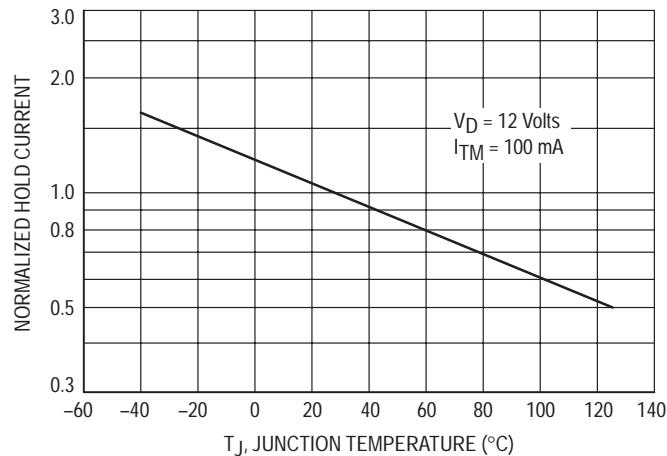
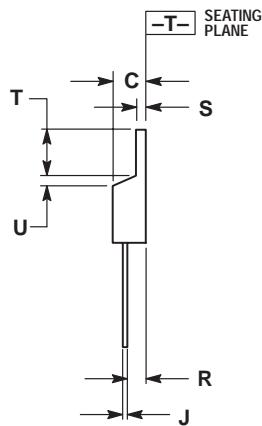
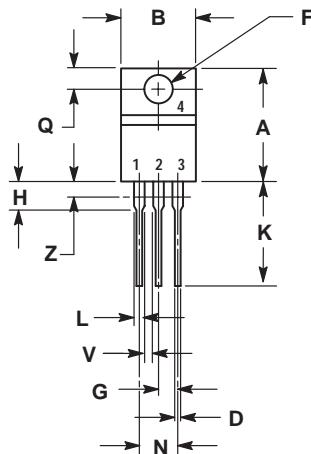


Figure 8. Holding Current

# MCR69-2, MCR69-3

## PACKAGE DIMENSIONS

**TO-220AB**  
CASE 221A-07  
ISSUE Z



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

| DIM | INCHES |       | MILLIMETERS |       |
|-----|--------|-------|-------------|-------|
|     | MIN    | MAX   | MIN         | MAX   |
| A   | 0.570  | 0.620 | 14.48       | 15.75 |
| B   | 0.380  | 0.405 | 9.66        | 10.28 |
| C   | 0.160  | 0.190 | 4.07        | 4.82  |
| D   | 0.025  | 0.035 | 0.64        | 0.88  |
| F   | 0.142  | 0.147 | 3.61        | 3.73  |
| G   | 0.095  | 0.105 | 2.42        | 2.66  |
| H   | 0.110  | 0.155 | 2.80        | 3.93  |
| J   | 0.014  | 0.022 | 0.36        | 0.55  |
| K   | 0.500  | 0.562 | 12.70       | 14.27 |
| L   | 0.045  | 0.060 | 1.15        | 1.52  |
| N   | 0.190  | 0.210 | 4.83        | 5.33  |
| Q   | 0.100  | 0.120 | 2.54        | 3.04  |
| R   | 0.080  | 0.110 | 2.04        | 2.79  |
| S   | 0.045  | 0.055 | 1.15        | 1.39  |
| T   | 0.235  | 0.255 | 5.97        | 6.47  |
| U   | 0.000  | 0.050 | 0.00        | 1.27  |
| V   | 0.045  | ---   | 1.15        | ---   |
| Z   | ---    | 0.080 | ---         | 2.04  |

STYLE 3:

1. CATHODE
2. ANODE
3. GATE
4. ANODE